Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3283	(magnetic adj memory).ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 07:08
L2	9	1 and (double adj junction)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 07:08
L3	5	("20010031374" | "20020000597" | "20020055016" | "6473336" | "6538917").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 07:13
L4	46	1 and (multiple adj layer)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 08:04
L5	29	1 and (micron).asn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 08:29
L6	157	1 and MRAM and array and write and read	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 08:30
L7	12	6 and (micron).asn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 08:33
L8	9	7 and (read with write)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 09:31
L9	0	7 and (wir$4 with pitch)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 09:32
L10	2	1 and (wir$4 with pitch)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 09:45
L11	888	semiconductor and memory and peripheral and (wir$4 with pitch)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 09:45
L12	56	11 and ((wir$4 with pitch) with different)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 09:46
L13	24	12 and wir$4.ab.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:15
L14	544	257/421.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:19
L15	262	257/422.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:39

L16	263	257/428.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:41
L17	1473	257/295.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:42
L18	45	(magnetic adj memory) and nakajima.in.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:42
L19	22	18 and wiring.clm.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:48
L20	4	18 and divided.clm.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 10:48
S1	161	(magnetic adj memory) and ((plural or multiple or divided) with (wiring or wire or conductor or wordline or bitline))	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 08:00
S2	8	S1 and (magnetic adj memory) and ((plural or multiple or divided) with (wiring or wire or conductor or wordline or bitline)).ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 07:07
S3	10	("20010025978" | "6236590" | "6331944" | "6404673" | "6480411" | "6498747" | "6504221").PN. OR ("6597049").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/08 18:30
S4	8	("5940319"|"5946228"|"5956267" |"6005800"|"6072718"|"6081445" |"6104633"|"6134139").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/08 18:30
S5	920	MRAM and step	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 08:01
S6	303	S5 and magnetic adj memory and (conductor or word or bit or wordline or bitline) and (step with (element or layer or memory))	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 08:08
S7	23	S6 and (step).ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 08:08